# XN0A312 (XN1A312)

# Silicon NPN epitaxial planer transistor (Tr1) Silicon PNP epitaxial planer transistor (Tr2)

## For switching/digital circuits

### Features

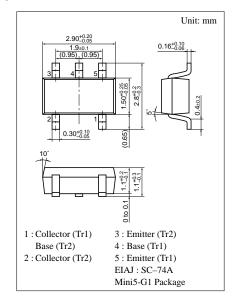
- Two elements incorporated into one package.
   (Transistors with built-in resistor, Tr1 collecter is connected to Tr2 base.)
- Reduction of the mounting area and assembly cost by one half.

#### Basic Part Number of Element

• UNR1212 (UN1212) + UNR1112 (UN1112)

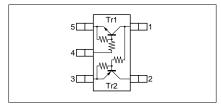
# Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Ratings	Unit	
Tr1	Collector to base voltage	$V_{CBO}$	50	V	
	Collector to emitter voltage	$V_{CEO}$	50	V	
	Collector current	$I_C$	100	mA	
Tr2	Collector to base voltage	$V_{CBO}$	-50	V	
	Collector to emitter voltage	$V_{CEO}$	-50	V	
	Collector current	$I_C$	-100	mA	
	Total power dissipation	$P_{T}$	300	mW	
Overall	Junction temperature	$T_{j}$	150	°C	
	Storage temperature	$T_{stg}$	-55 to +150	°C	



Marking Symbol: 4P

#### Internal Connection



# ■ Electrical Characteristics (Ta=25°C)

# • Tr1

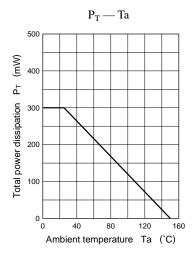
Parameter	Symbol	Conditions	min	typ	max	Unit
Collector to base voltage	V <sub>CBO</sub>	$I_{\rm C} = 10 \mu A, I_{\rm E} = 0$	50			V
Collector to emitter voltage	V <sub>CEO</sub>	$I_C = 2mA$ , $I_B = 0$	50			V
C-114	$I_{CBO}$	$V_{CB} = 50V, I_E = 0$			0.1	μА
Collector cutoff current	I <sub>CEO</sub>	$V_{CE} = 50V, I_{B} = 0$			0.5	μА
Emitter cutoff current	$I_{EBO}$	$V_{EB} = 6V, I_C = 0$			0.2	mA
Forward current transfer ratio	h <sub>FE</sub>	$V_{CE} = 10V, I_C = 5mA$	60			
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0.3 {\rm mA}$			0.25	V
Output voltage high level	V <sub>OH</sub>	$V_{CC} = 5V, V_{B} = 0.5V, R_{L} = 1k\Omega$	4.9			V
Output voltage low level	V <sub>OL</sub>	$V_{CC} = 5V, V_{B} = 2.5V, R_{L} = 1k\Omega$			0.2	V
Transition frequency	$f_T$	$V_{CB} = 10V, I_E = -1mA, f = 200MHz$		150		MHz
Input resistance	R <sub>1</sub>		-30%	22	+30%	kΩ
Resistance ratio	$R_1/R_2$		0.8	1.0	1.2	

# • Tr2

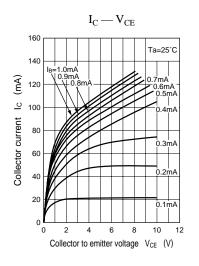
Parameter	Symbol	Conditions	min	typ	max	Unit
Collector to base voltage	V <sub>CBO</sub>	$I_{\rm C} = -10\mu A, I_{\rm E} = 0$	-50			V
Collector to emitter voltage	V <sub>CEO</sub>	$I_C = -2mA$ , $I_B = 0$	-50			V
Collector cutoff current	$I_{CBO}$	$V_{CB} = -50V, I_E = 0$			- 0.1	μА
Collector cutoff current	I <sub>CEO</sub>	$V_{CE} = -50V, I_B = 0$			- 0.5	μА
Emitter cutoff current	I <sub>EBO</sub>	$V_{EB} = -6V, I_C = 0$			- 0.2	mA
Forward current transfer ratio	h <sub>FE</sub>	$V_{CE} = -10V, I_{C} = -5mA$	60			
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = -10 \text{mA}, I_{\rm B} = -0.3 \text{mA}$			- 0.25	V
Output voltage high level	V <sub>OH</sub>	$V_{CC} = -5V, V_B = -0.5V, R_L = 1k\Omega$	-4.9			V
Output voltage low level	V <sub>OL</sub>	$V_{CC} = -5V, V_B = -2.5V, R_L = 1k\Omega$			- 0.2	V
Transition frequency	$f_T$	$V_{CB} = -10V$ , $I_E = 1mA$ , $f = 200MHz$		80		MHz
Input resistance	R <sub>1</sub>		-30%	22	+30%	kΩ
Resistance ratio	$R_1/R_2$		0.8	1.0	1.2	

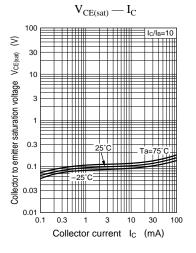
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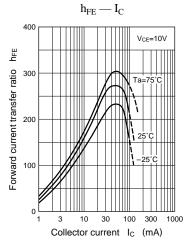
#### Common characteristics chart

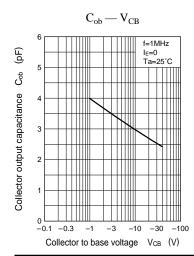


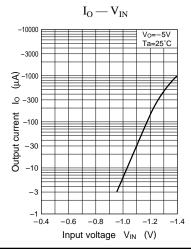
#### Characteristics charts of Tr1

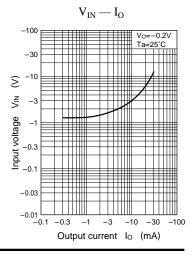




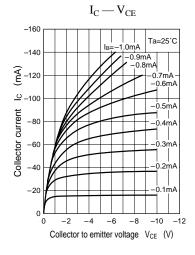


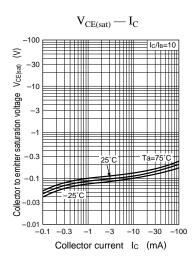


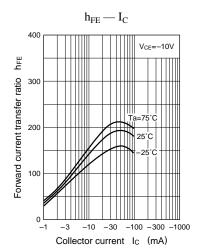


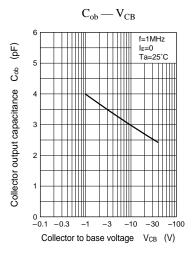


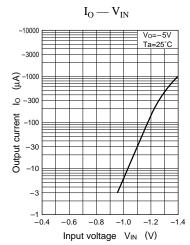
#### Characteristics charts of Tr2

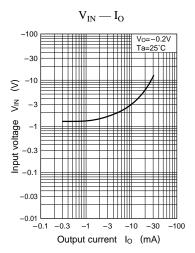












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